### Switch-mode Power Rectifiers

This series is designed for use in switching power supplies, inverters and as free wheeling diodes.

### Features

- Ultrafast 25 and 50 Nanosecond Recovery Time
- 175°C Operating Junction Temperature
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Low Forward Voltage
- Low Leakage Current
- Reverse Voltage to 600 V
- ESD Ratings:
  - Machine Model = C (> 400 V)
  - Human Body Model = 3B (> 16,000 V)
- SUR8 Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant\*

### **Mechanical Characteristics:**

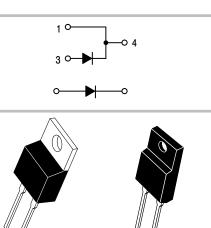
- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max for 10 Seconds



### **ON Semiconductor®**

http://onsemi.com

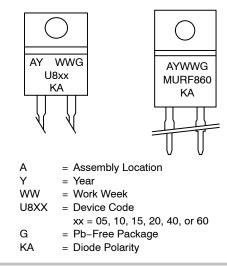
### ULTRAFAST RECTIFIERS 8.0 AMPERES, 50–600 VOLTS



TO-220AC CASE 221B STYLE 1

TO-220 FULLPAK CASE 221AG STYLE 1

#### MARKING DIAGRAMS



### **ORDERING INFORMATION**

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

### **MAXIMUM RATINGS**

		MUR/SUR8						
Rating	Symbol	805	810	815	820	840	860	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	150	200	400	600	V
Average Rectified Forward Current Total Device, (Rated V <sub>R</sub> ), T <sub>C</sub> = 150°C	I <sub>F(AV)</sub>	8.0			A			
Peak Repetitive Forward Current (Rated $V_R$ , Square Wave, 20 kHz), $T_C$ = 150°C	I <sub>FM</sub>	16			A			
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I <sub>FSM</sub>	100		A				
Operating Junction Temperature and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +175		°C				

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

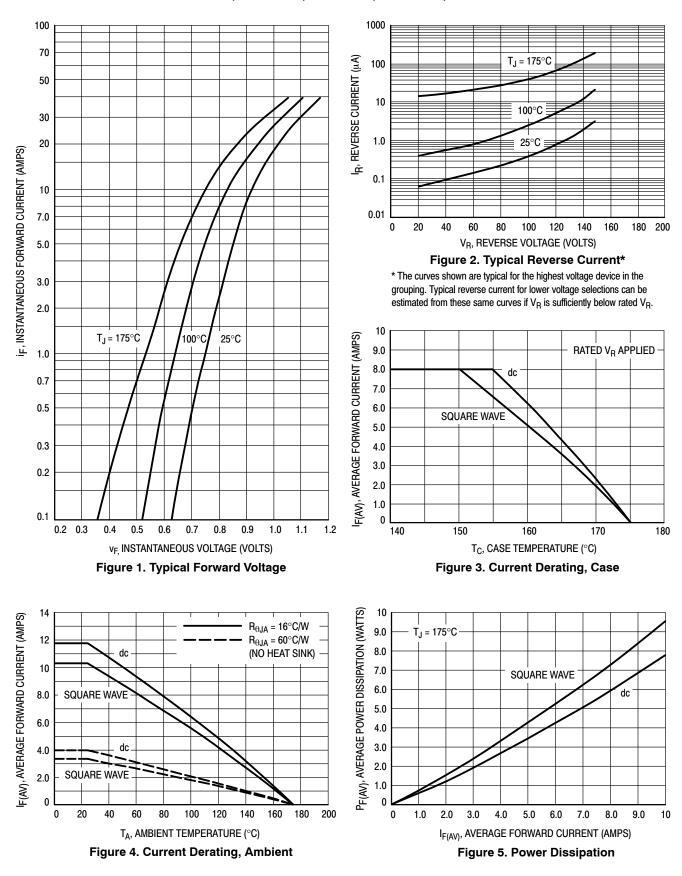
### **THERMAL CHARACTERISTICS**

		MUR/SUR8						
Characteristic	Symbol	805	810	815	820	840	860	Unit
Maximum Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	3.0		2.0		°C/W		
Thermal Resistance, Junction-to-Case MURF860	R <sub>θJC</sub>	4.75				°C/W		
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	73		°C/W				
Thermal Resistance, Junction-to-Ambiente MURF860	$R_{ hetaJA}$	75		°C/W				

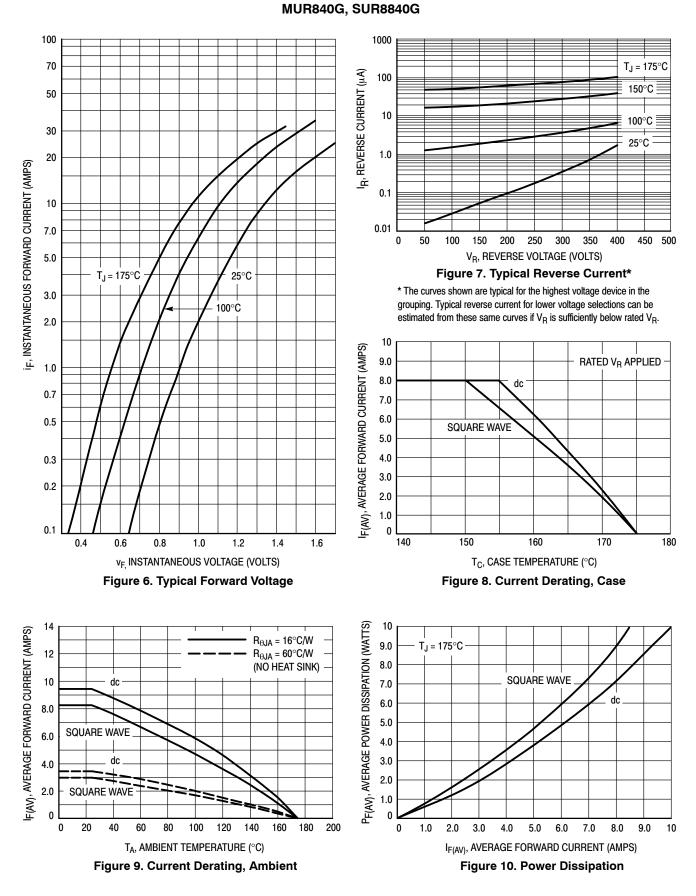
### **ELECTRICAL CHARACTERISTICS**

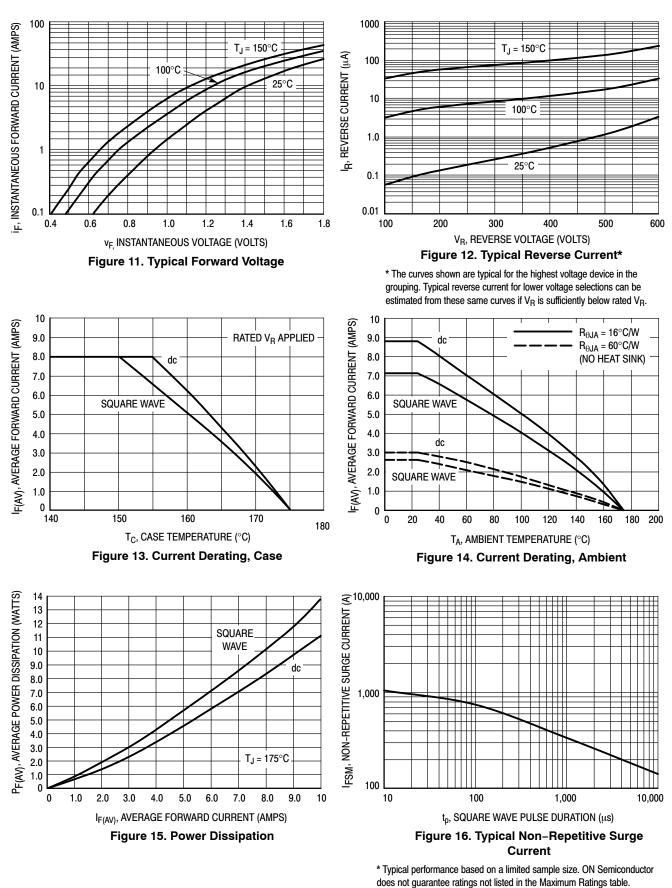
		MUR/SUR8						
Characteristic	Symbol	805	810	815	820	840	860	Unit
Maximum Instantaneous Forward Voltage (Note 1) ( $i_F = 8.0 \text{ A}, T_C = 150^{\circ}\text{C}$ ) ( $i_F = 8.0 \text{ A}, T_C = 25^{\circ}\text{C}$ )	VF		8.0 9.0			1.00 1.30	1.20 1.50	V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, $T_J = 150^{\circ}C$ ) (Rated DC Voltage, $T_J = 25^{\circ}C$ )	i <sub>R</sub>	250 5.0		50 1		μΑ		
	t <sub>rr</sub>	35 25		6 5	-	ns		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Pulse Test: Pulse Width =  $300 \ \mu$ s, Duty Cycle  $\leq 2.0\%$ .

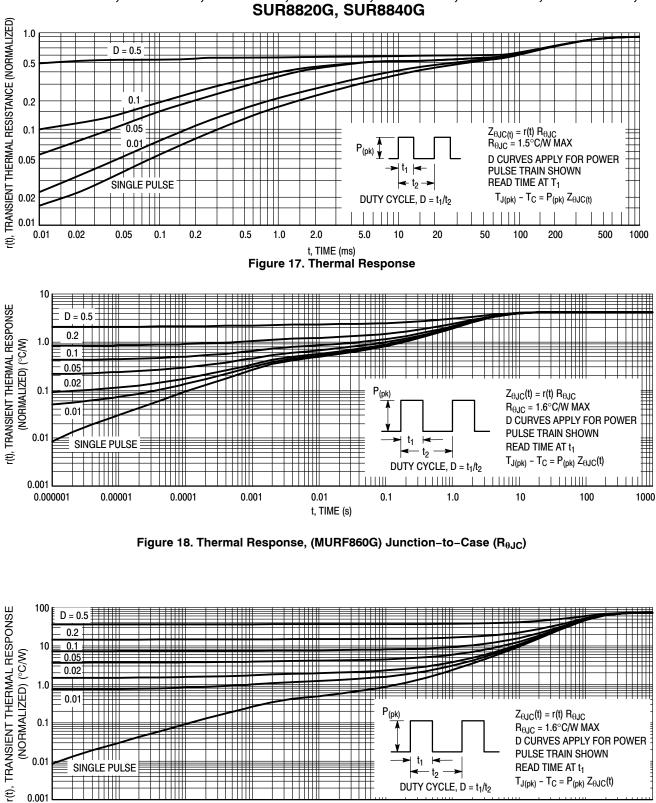


MUR805G, MUR810G, MUR815G, MUR820G, SUR8820G





MUR860G, MURF860G



## MUR805G, MUR810G, MUR815G, MUR820G, MUR840G, MUR860G, MURF860G,

Figure 19. Thermal Response, (MURF860G) Junction-to-Ambient (R<sub>0JA</sub>)

t, TIME (s)

0.01

10

1.0

0.1

0.01

0.001 0.000001

(NORMALIZED) (°C/W)

0.1

TTTII

0.00001

SINGLE PULSE

ΤШ

0.05

0.02

0.01

0.0001

0.001

1

t<sub>1</sub> 

∙t<sub>2</sub> →

DUTY CYCLE,  $D = t_1/t_2$ 

1.0

D CURVES APPLY FOR POWER

100

1000

 $Z_{\Theta JC}(t) = r(t) R_{\Theta JC}$ 

READ TIME AT t1

10

 $R_{\theta JC} = 1.6^{\circ}C/WMAX$ 

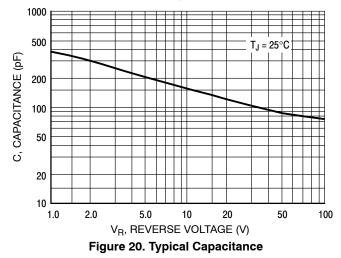
PULSE TRAIN SHOWN

 $T_{J(pk)} - T_C = P_{(pk)} Z_{\Theta JC}(t)$ 

-----

P<sub>(pk)</sub>

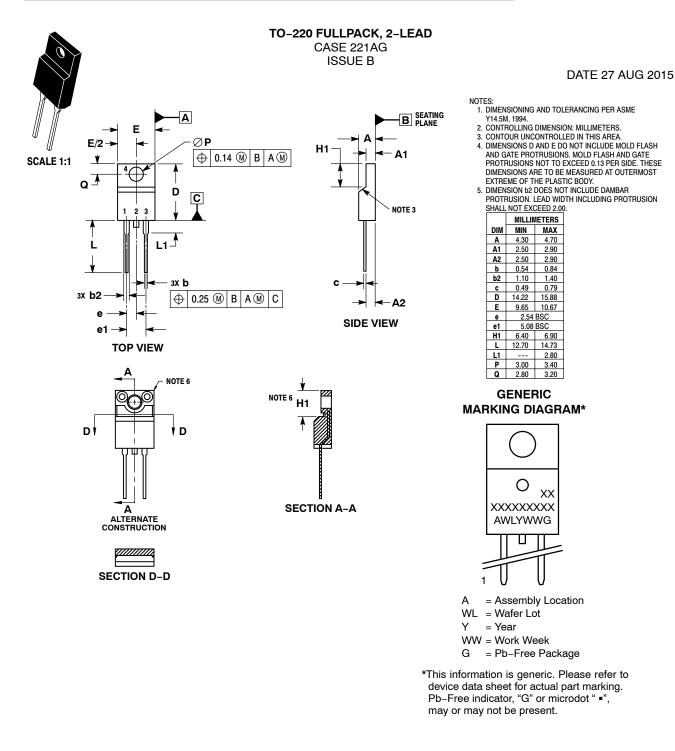
0.1



### **ORDERING INFORMATION**

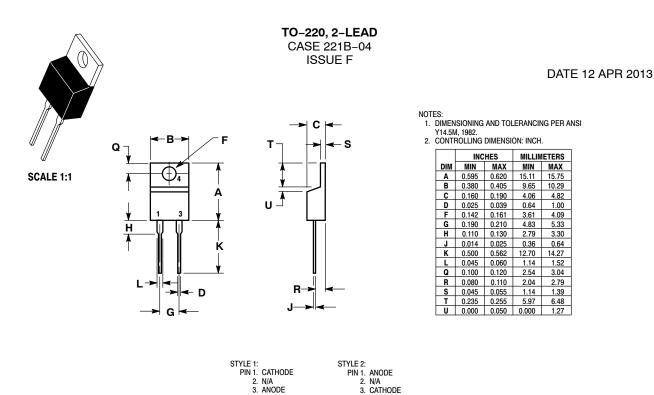
Device	Package	Shipping
MUR805G	TO-220AC (Pb-Free)	50 Units / Rail
MUR810G	TO-220AC (Pb-Free)	50 Units / Rail
MUR815G	TO-220AC (Pb-Free)	50 Units / Rail
MUR820G	TO-220AC (Pb-Free)	50 Units / Rail
SUR8820G	TO-220AC (Pb-Free)	50 Units / Rail
MUR840G	TO-220AC (Pb-Free)	50 Units / Rail
SUR8840G	TO-220AC (Pb-Free)	50 Units / Rail
MUR860G	TO-220AC (Pb-Free)	50 Units / Rail
MURF860G	TO-220FP (Pb-Free)	50 Units / Rail





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